NSN 5961-01-509-1311

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Inclosure Material:

Metal

Overall Length:

Between 1.328 inches and 1.358 inches

Overall Diameter:

0.875 inches

End Application:

C-17a aircraft

Mounting Facility Quantity:

2

Mounting Method:

Terminal and unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

170.0 collector to base voltage/static/emitter open and 150.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

Between 16.00 amperes source cutoff current and 30.00 amperes zero-gate-voltage source current blank and 4.00 amperes source cutoff

current and 15.00 amperes zero-gate-voltage source current of standard range

Power Rating Per Characteristic:

250.0 watts small-signal input power, common-emitter outside diameter

Product Name:

Transistor, silicon, n-p-n, high current

Terminal Type And Quantity:

2 pin and 2 unthreaded hole

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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